

HZK-LL Series

Silicon Epitaxial Planar Zener Diodes for Hard Knee Low Noise

> REJ03G0020-0200Z (Previous: ADE-208-128A)

> > Rev.2.00 May.14.2003

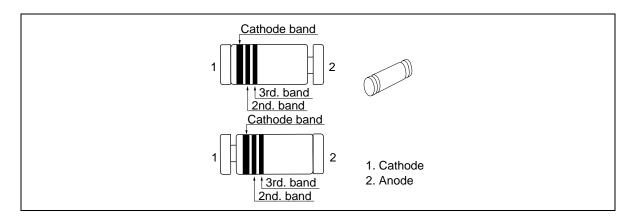
Features

- Low dynamic impedance and low noise in the low current region (approximately 1/10 lower than the current zeners).
- LLD package is suitable for high density surface mounting and high speed assembly.

Ordering Information

| Type No. | Mark | Package Code |
|---------------|------------|--------------|
| HZK-LL Series | Color Code | LLD |

Pin Arrangement



Absolute Maximum Ratings

 $(Ta = 25^{\circ}C)$

| Item | Symbol | Value | Unit |
|----------------------|--------|-------------|------|
| Power dissipation | Pd * | 250 | mW |
| Junction temperature | Tj | 175 | °C |
| Storage temperature | Tstg | -55 to +175 | °C |

Note: With P.C. Board.

Electrical Characteristics

 $(Ta = 25^{\circ}C)$

| | | V _z (V | /) * ¹ | | I _R (n | A) | Z _{zt} (C | 2) | $\mathbf{Z}_{ZK}^{ \ *^2}$ | (kΩ) | $^{*3}\Delta V_{z_1}(V)$ | $^{*4}\Delta V_{z_2}(V)$ |
|--------|-------|-------------------|-------------------|---------------------|-------------------|--------------------|-----------------------------------|----------------------|-----------------------------|----------------------|--------------------------|--------------------------|
| Type | Grade | Min | Max | I _z (mA) | Max | V _R (V) | Max | I _{ZT} (mA) | Тур | I _{zκ} (μΑ) | Max | Max |
| HZK2LL | Α | 1.6 | 2.0 | 0.5 | 100 | 0.5 | 350 | 0.5 | (1.2) | 50 | 0.5 | 0.6 |
| | В | 1.9 | 2.3 | _ | | | | | | | | |
| | С | 2.2 | 2.6 | | | | | | | | | |
| HZK3LL | Α | 2.5 | 2.9 | 0.5 | 100 | 1.0 | 360 | 0.5 | (1.2) | 50 | 0.5 | 0.6 |
| | В | 2.8 | 3.2 | _ | | | | | | | | |
| | С | 3.1 | 3.5 | _ | | | | | | | | |
| HZK4LL | Α | 3.4 | 3.8 | 0.5 | 100 | 2.0 | 370 | 0.5 | (1.5) | 50 | 0.5 | 0.6 |
| | В | 3.7 | 4.1 | _ | | | | | | | | |
| | С | 4.0 | 4.4 | _ | | | | | | | | |
| HZK5LL | Α | 4.3 | 4.7 | 0.5 | 100 | 3.0 | 380 | 0.5 | (1.5) | 50 | 0.5 | 0.6 |
| | В | 4.6 | 5.0 | _ | | | | | | | | |
| | С | 4.9 | 5.3 | _ | | | | | | | | |

Notes: 1. Tested with DC.

- 2. Reference only
- 3. $\Delta V_{z_1} = V_z (I_z = 0.5 \text{ mA}) V_{z_1} (I_z = 0.05 \text{ mA})$
- 4. $\Delta V_{z2} = V_{z1} (I_z = 0.05 \text{ mA}) V_{z2} (I_z = 0.001 \text{ mA})$

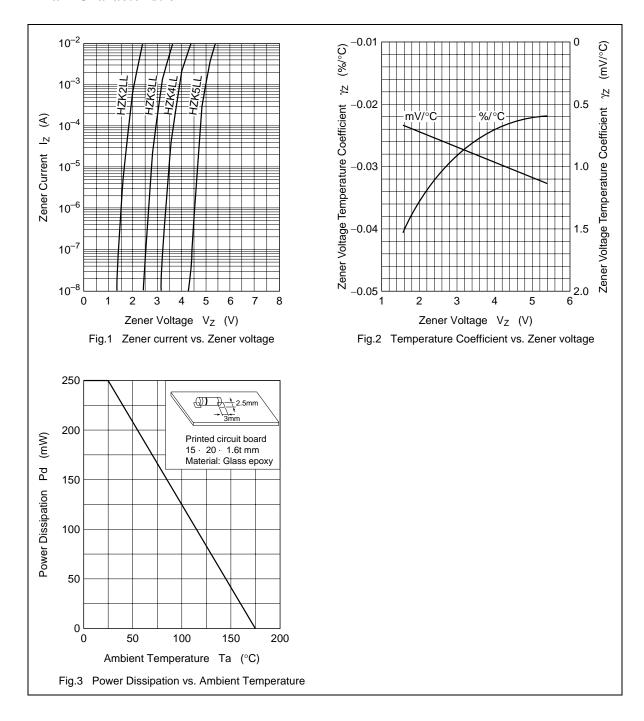
Type No. is as follows; HZK2ALL, HZK2BLL, ••• HZK5CLL.

HZK-LL Series

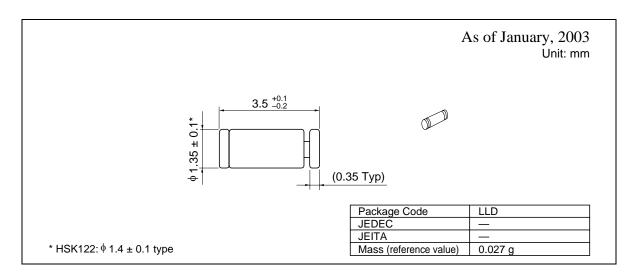
Mark Color Code

| Туре | Cathode Band | Second Band | Third Band |
|---------|--------------|--------------|------------|
| HZK2ALL | Verdure | Yellow Ocher | Pink |
| HZK2BLL | Verdure | Yellow Ocher | Blue |
| HZK2CLL | Verdure | Yellow Ocher | Light Blue |
| HZK3ALL | Verdure | Pink | Pink |
| HZK3BLL | Verdure | Pink | Blue |
| HZK3CLL | Verdure | Pink | Light Blue |
| HZK4ALL | Verdure | Orange | Pink |
| HZK4BLL | Verdure | Orange | Blue |
| HZK4CLL | Verdure | Orange | Light Blue |
| HZK5ALL | Verdure | Yellow | Pink |
| HZK5BLL | Verdure | Yellow | Blue |
| HZK5CLL | Verdure | Yellow | Light Blue |

Main Characteristic



Package Dimensions



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